

#### **Features**

- High Density Cell Desihn for Ultra Low R<sub>DS(on)</sub>
- · Fully Characterized Avalanche Voltage and Current
- Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

# **Maximum Ratings**

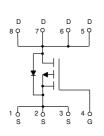
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 3.57°C/W Junction to Case<sup>(Note 2)</sup>

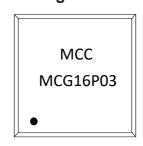
Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V <sub>DS</sub>	-30	V
Gate-Source Volltage		V <sub>GS</sub>	±20	V
Continuous Drain Current	T <sub>C</sub> =25°C	1	-16	Α
	T <sub>C</sub> =100°C	l <sub>D</sub>	-12	Α
Pulsed Drain Current (Note 3)		I <sub>DM</sub>	-80	Α
Single Pulse Avalanche Energy (Note 4)		E <sub>AS</sub>	90	mJ
Total Power Dissipation		P <sub>D</sub>	35	W

#### Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. Surface Mounted on FR4 Board, t≤10 sec.
- 3. Pulse Width Limited by Maximum Junction Temperature.
- 4. EAS Condition: T\_J=25°C, V\_DD=-15V, V\_G=-4.5V, L=0.5 mH, Rg=25  $\Omega$ .

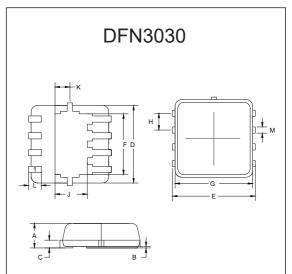
# **Internal Structure and Marking Code**





Pin1

# P-CHANNEL MOSFET



DIMENSIONS						
DIM INCHES		HES	MM		NOTE	
	MIN	MAX	MIN	MAX	NOTE	
Α	0.028	0.035	0.70	0.90		
В	0.000	0.002	0.00	0.05		
С	0.004	0.010	0.10	0.25		
D	0.118		3.00		TYP.	
E	0.126		3.20		TYP.	
F	0.093		2.35		TYP.	
G	0.118		3.00		TYP.	
Н	0.026		0.65		TYP.	
J	0.069		1.75		TYP.	
K	0.023		0.575		TYP.	
L	0.012	0.020	0.30	0.50		
M	0.009	0.014	0.24	0.35	_	



# Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA	-30	-33		V
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V			-1	μA
Gate-Threshold Voltage <sup>(Note 5)</sup>	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	-1	-1.5	-1.9	V
Drain-Source On-Resistance <sup>(Note 5)</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-15A		10.6	15	m-0
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-15A		16.3	25	mΩ
Forward Tranconductance <sup>(Note 5)</sup>	<b>g</b> <sub>FS</sub>	V <sub>DS</sub> =-5V, I <sub>D</sub> =-15A	15			S
Dynamic Characteristics(Note 6)						
Input Capacitance	C <sub>iss</sub>			2130		pF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =-25V,V <sub>GS</sub> =0V,f=1MHz		302		
Reverse Transfer Capacitance	C <sub>rss</sub>			227		
Total Gate Charge	Qg			45.6		
Gate-Source Charge	$Q_{gs}$	V <sub>DS</sub> =-15V,V <sub>GS</sub> =-10V,I <sub>D</sub> =-20A		4.6		nC
Gate-Drain Charge	$Q_{gd}$			11.1		
Turn-On Delay Time	t <sub>d(on)</sub>			12		
Turn-On Rise Time	t <sub>r</sub>	$V_{DD}$ =-15V, $I_{D}$ =-15A $V_{GS}$ =-10V, $R_{GEN}$ =1 $\Omega$		10		ns
Turn-Off Delay Time	t <sub>d(off)</sub>			25		
Turn-Off Fall Time	t <sub>f</sub>			13		
Drain-Source Body Diode Characteristics						
Body Diode Voltage (Note 5)	V <sub>SD</sub>	I <sub>SD</sub> =-30A, V <sub>GS</sub> =0V			-1.2	V

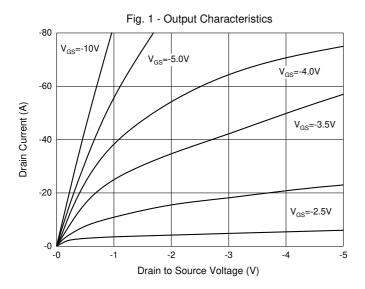
## Note:

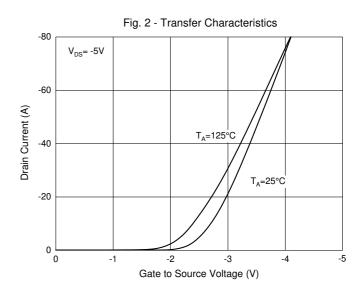
<sup>5.</sup> Pulse Test : Pulse Width≤300µs, Duty Cycle ≤2%.

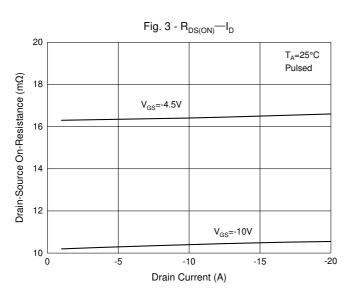
<sup>6.</sup> Guaranteed by Design, Not Subject to Production Testing.

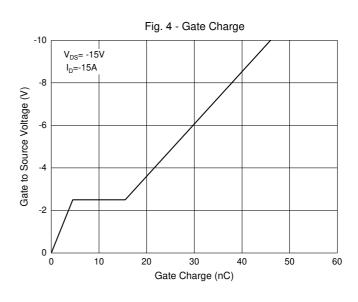


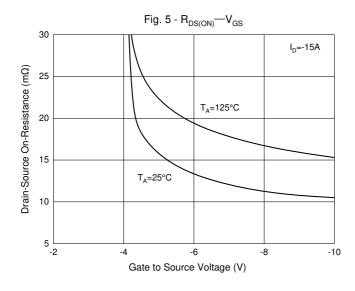
#### **Curve Characteristics**

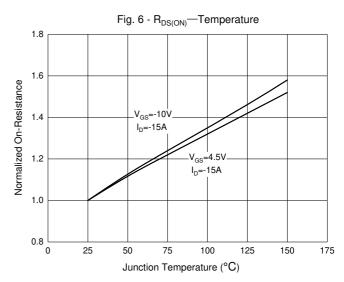














## **Ordering Information**

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

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